# **Quantum efficiency of flat metallic cathodes under** varying electric fields and tunable laser illumination

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# Introduction

Highly brilliant electron sources are crucial for the performance of future free electron lasers [1]. Photo-induced field emission (PFE) might combine the high peak currents of photo cathodes with the low emittance of field emitted electrons. Previous investigations of PFE were performed on tip cathodes and yielded a high brilliance B  $\leq 1 \times 10^{13} \text{ A/m}^2 \text{ rad}^2$ , low emittance  $\varepsilon_{x,y} < 7 \cdot 10^{-7} \text{ m rad but}$ only low currents I  $\leq$  2.9 A and parasitic field emission [2]. The systematic investigation of the PFE process requires monochromatic illumination and energy spectroscopy of the emitted electrons. A new UHV analysis system for PFE-spectroscopy (PFES) has been constructed [3].

First results on quantum efficiency (QE, emitted electrons per photon) and different emission regimes of electrons for flat gold and silver crystals are presented.

# **Basic principles**

### Field emission (FE)

### **Photoemssion (PE)**

• tunnelling of electrons into vacuum due to an • three-steps-model: (i) absorption of a photon;

## Au(111) sample

- no FE for E < 8.9 MV/m
- FE measurement for higher E: field enhancement

Results

- $\beta = 500 \pm 11$ , emitting surface S = 106 ± 22 µm<sup>2</sup>
- laser pulse energy: 50 160 µJ
- $E_{eff, 5.3 \text{ MV/m}} = \beta E = 2630 \text{ MV/m} \rightarrow \Delta \Phi_{Schottky} > 1.9 \text{ eV}$ but no strong decrease of  $\Phi$  observed
- $\rightarrow$  high  $\beta$  due to particles on surface
- pure PE for E = 1.8 MV/m and 3.6 MV/m
- PE: work function  $\Phi = 4,66 \pm 0,7 \text{ eV}$  $(\Phi_{\text{lit}} = 5.1 \text{ eV for polycrystalline Au})$  [9]  $\rightarrow$  low  $\Phi$  due to adsorbats?
- for hv < 5.3 eV hints for resonant optical transitions
- $E \ge 5.3 \text{ MV/m} \rightarrow \text{more than 3 times higher QE}$
- Enhanced PE for  $E \ge 5.3$  MV/m due to slight lowering of  $\Phi$





- applied electric field
- I ~  $\exp(-B\Phi_0^{3/2}/E)$ , B = const.
- low transverse momentum of emitted electrons transverse momentum of electrons is conserved
  - $\rightarrow$  low emittance  $\varepsilon_{xy}$
- nanosecond bunches in rf guns
- lifetime ~ O(years)
- (ii) transport to surface; (iii) emission •  $W_{kin} = hv - \Phi_0 - W_B$ → high emittance  $\epsilon_{x,v}$  (hv –  $\Phi_0$  > 1 eV usually) • short pulse length possible (depends on laser pulse)
  - lifetime ~ O(month) (P < 10<sup>-10</sup> mbar)

### **Photo-induced field emission (PFE)**

- photonic illumination of FE cathodes with  $h_V < \Phi_0 \Delta \Phi_{Schottkv}$
- excitation of electrons to energies below  $\Phi_0 \Delta \Phi_{\text{Schottky}}$
- higher emission current due to increased tunneling probability at  $W = W_F + \Delta \Phi$
- sub-picosecond bunches possible with pulsed illumination [4]



Schematic of the FE, PE, SPE and PFE processes with energy distributions of the emitted electrons.

- hv = 4.7 5.3 eV and  $E \ge 5.3 \text{ MV/m}$  $\rightarrow$  exponential increase of PFE !?
  - proof: plot of log(QE) vs. hv with linear fit

### Ag(111) sample

- no pure FE for E < 12 MV/m</li>
- laser pulse energy: 280 980 µJ
- clear peaks at 5.30 eV, 5.54 eV and 5.88 eV due to resonant transitions in bandstructure? (see bandstructure below [10])
- further peaks between 4.6 eV and 5.0 eV
- QE measurements at hv = 4.68 eV with varying E show a exponential rise of QE (see plot below)  $\rightarrow$  hint for PFE?
- further measurements with varying E reveal QE ~  $E^{1/2}$  for relatively low fields and pure PE (see plot bottom right)





5.17

### **Possible PFE processes**

- tunneling of electrons from excited states at  $W_F + hv$  [5,6]
- relaxation of the photo-excited electrons to states above  $W_F$ , resulting in  $\Delta \Phi < h_V$  [7,8]
- immediate tunnelling of excited electrons without existence of electronic states?



- tiltable gate ( $\alpha = \pm 5^\circ$ ,  $\Delta \alpha = 0.003^\circ$ )
- E  $\leq$  400 MV/m @  $\Delta z = 50 \mu m$ , U = 20 kV
- hemispherical energy analyzer ( $\Delta E < 50 \text{ meV}$ ).

- laser pulse energy: 80 200 µJ
- detailed measurements plotted in two different ways (contour plot & 3D surface)
- $QE \sim E^{1/2}$
- increase of QE at 4.52 eV= $\Phi_{110,\text{Lit}}$  [9]  $\rightarrow$  fermi-edge
- resonances for hv < 5.6 eV not as clear as the ones revealed for Ag(111)
- dominant peak at ~5.85 eV due to optical transition that leads to preferred emission from Ag(110) (see bandstructure)



-100

\_ 80

60

20

EMMIM

# **Conclusions and Outlook**

QE measurements on Au and Ag crystals showed resonant optical transitions (PE) hints for PFE observed for Au(111) and Ag(111) (exponential increase of QE with E and  $h_V$ )

### cathode illumination:

• Nd:YAG Laser ( $\leq$  70 mJ @ 355 nm) pumping tuneable OPO (optical parametric oscillator) • 210 nm  $\leq \lambda \leq$  2300 nm, gap free • t<sub>pulse</sub> = 3.5 ns, f<sub>rep</sub> = 10 Hz



# Au and Ag crystal sampels

### Au sample

#### • Au(111)-bulk

 mechanically polished to roughness rms ~ 31 nm • heated @ 800 °C in the atmosphere (cleaning & recrystallisation) • XRD: surface: ~ 60 % Au(111) and ~ 33% Au(100) • in situ cleaned with 4 keV Ar+-lons

### Ag samples

- Ag(111)-bulk
  - mechanically polished to roughness rms ~ 15 nm
  - heated @ 780 °C in the atmosphere
  - XRD: surface ~ 84 % Ag(111)
  - UPS: Φ=4,61 (Φ<sub>Lit.111</sub>=4,74 eV) [9]



#### •Ag(110)-bulk

- mechanically polished to roughness rms ~ 15 nm heated @ 630 °C and 10<sup>-7</sup> mbar
- XRD: surface ~ 52 % Ag(110)
- and ~ 10 % Ag(311), (331), (420)

#### Future investigations:

- better surface preparation necessary (chem. polishing, in situ heating, cleanroom technology, ...)
- spectroscopy of emitted electrons
  - clear distinction between emission regimes
  - certain identification of optical transitions in bandstructure
- further systematic variation of relevant parameters ( $P_{Laser}$ ,  $T_{cathode}$ , ...)
- test of various materials with different electronic structures (metals, semiconductors, alloys)
- for high QE: test metal oxide crystals!
- emittance measurements of optimized cathode materials (e.g. DESY Zeuthen, FZR Dresden)

### **References & Acknowledgements**

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